

#### **Features:**

- 1200V Schottky Diode
- Zero Reverse Recovery Current
- High Frequency Operation
- Positive Temperature Coefficient
- Temperature independent Switching

# **Applications:**

- Switch Mode Power Supply
- Booster diodes in PFC, DC/DC
- AC/DC converters

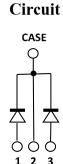
## **Benefits:**

- Unipolar Rectifier
- Minimal switching loss
- Higher Efficiency
- Low cooling requirement

Symbol	Value	Unit			
V <sub>RRM</sub>	1200	V			
$I_F \ (Tc = 155^{\circ}C)$	10	А			
*Qc	26	nC			



**TO-247-3** 



Maximum	Ratings	(*Per leg)
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Symbol	Parameter	Value	Unit	Test Conditions
VR	DC Peak Reverse Voltage	1200	v	$T_J = 25^{\circ}C$
V <sub>RRM</sub>	Repetitive Peak Reverse	1200	V	$T_J = 25^{\circ}C$
V <sub>RSM</sub>	Surge Peak Reverse Voltage	1300	V	$T_J = 25^{\circ}C$
I <sub>F</sub>	Continuous Forward Current	*16/32 *7.5/15 *5/10	А	$T_{\rm C} = 25^{\circ}{\rm C}$ $T_{\rm C} = 135^{\circ}{\rm C}$ $T_{\rm C} = 155^{\circ}{\rm C}$
I <sub>FRM</sub>	Repetitive Peak Forward Surge Current	*41 *37	А	$T_{\rm C} = 25^{\circ}$ C, $T_{\rm P} = 10$ ms, Half Sine Wave Tc = 125°C, $T_{\rm P} = 10$ ms, Half Sine Wave
I <sub>FSM</sub>	Non-Repetitive Peak Forward Surge Current	*54 *49	А	$T_{\rm C}$ =25°C, $T_{\rm P}$ = 10ms, Half Sine Wave Tc = 125°C, $T_{\rm P}$ = 10ms, Half Sine Wave
PD	Power Dissipation	*81 *27	W	$T_{\rm C} = 25^{\circ}{\rm C}$ $T_{\rm C} = 125^{\circ}{\rm C}$
T <sub>J,max</sub>	Operating Junction Temperature	175	°C	
T <sub>stg</sub>	Storage Temperature Range	-55 to 175	°C	

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### Thermal characteristics (\*Per leg)

Symbol	Parameter	Min.	Тур.	Max.	Unit
RthJC	Thermal resistance		*1.8/0.9		°C/W

#### **Electrical Characteristics (Per leg)**

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Symbol	Parameter	Min.	Тур.	Max.	Unit	Test Conditions
VDC	DC Blocking Voltage	1200			V	$I_R = 100 \mu A, T_J = 25^{\circ}C$
V <sub>F</sub>	Forward Voltage		1.55	1.9	V	$I_F = 10A, T_J = 25^{\circ}C$
▼ F	Forward Voltage		2.4	2.7	v	$I_F = 10A, T_J = 175^{\circ}C$
I <sub>R</sub>	Reverse Current		3	100	μΑ	$V_{R} = 1200V, T_{J} = 25^{\circ}C$
IR	Reverse Current		15	500		$V_R = 1200V, T_J = 175^{\circ}C$
Qc	Total Capacitive Charge		26		nC	$Q_C = \int_0^{V_R} C dV$ Tj=25°C, V <sub>R</sub> =800V
			168			$V_R = 1V, T_J = 25^{\circ}C, f = 1 \text{ MHz}$
С	Total Capacitance		31 28		pF	$V_R = 400V, T_J = 25^{\circ}C, f = 1 \text{ MHz}$ $V_R = 800V, T_J = 25^{\circ}C, f = 1 \text{ MHz}$

#### **Typical Performance (Per leg)**

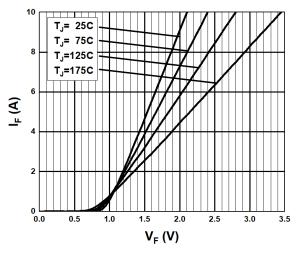


Fig. 1 Forward Characteristics

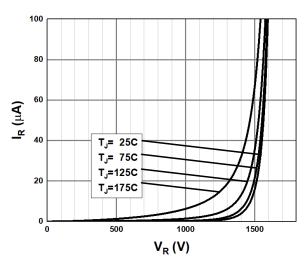
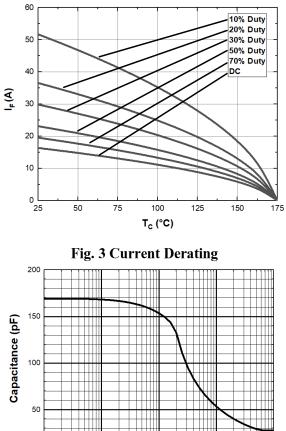


Fig. 2 Reverse Characteristics



**Typical Performance (per leg)** 



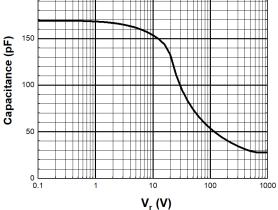


Fig. 5 Capacitance vs. Reverse Voltage

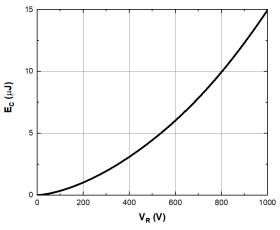


Fig. 7 Capacitance stored Energy

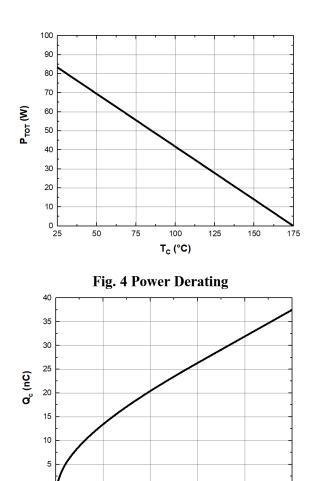


Fig. 6 Recovery Charge vs. Reverse Voltage

V<sub>R</sub> (V)

600

400

0

0

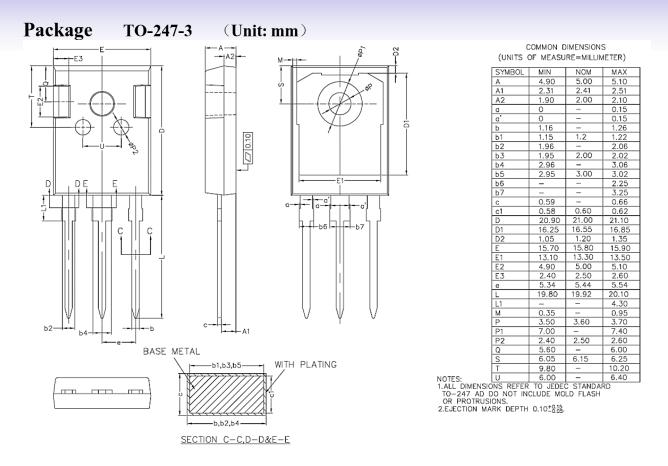
200



800

1000





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